

# LISY300AL

MEMS inertial sensor:

single-axis ±300°/s analog output yaw rate gyroscope

## **Features**

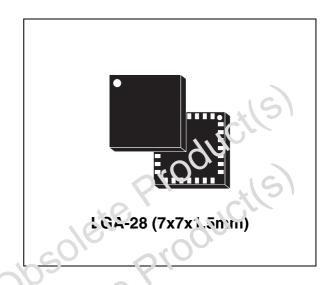
- 2.7 V to 3.6 V single supply operation
- Low power consumption
- Embedded power-down
- ±300 °/s full scale
- Absolute analog rate output
- Integrated low-pass filters
- Embedded self-test
- High shock survivability
- ECOPACK<sup>®</sup> RoHS and "Green" compliant (see *Section 4*)



The LISY300AL is a low-power single-axis yaw rate sensor. It includes a sensing element and an IC interface able to provide the measured angular rate to the external world through an acaing output voltage.

The sensing element, capable of detecting the yaw rate, is manufactured using a dedicared micromachining process developed by ST to produce inertial sensors and actualizes on silicon wafers.

There interface is manufactured using a CMOS process that allows a nigh level of integration to design a dedicated circuit which is trimmed to better match the sensing element characteristics.



The LISY30 A! nas a full scale of ±300 °/s and is capable ວິ measuring rates with a -3 dB bar ໝາວໃດ up to 88 Hz.

The LISY300AL is available in a plastic land grid array (LGA) package and can operate within a temperature range from -40 °C to +85 °C.

The LISY300AL belongs to a family of products suitable for a variety of applications, including:

- Gaming and virtual reality input devices
- Motion control with MMI (man-machine interface)
- Image stabilization for digital video and digital still cameras
- GPS navigation systems
- Appliances and robotics

**Table 1. Device summary** 

Order code	Temperature range (°C)	Package	Packing
LISY300AL	-40 to +85	LGA-28 (7x7x1.5)	Tray
LISY300ALTR	LISY300ALTR -40 to +85		Tape and reel

May 2008 Rev 1 1/13

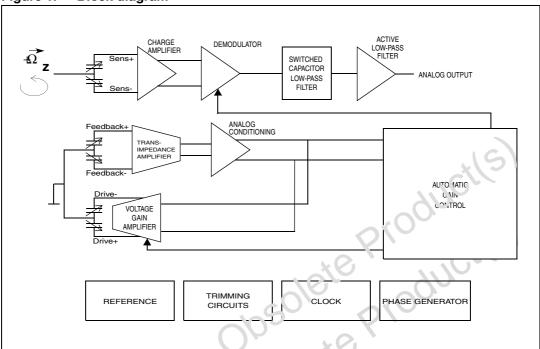
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# 1 Block diagram and pin description

Figure 1. Block diagram



The vibration of the structure is maintained by a drive circuitry in a feedback loop. The sensing signal is filtered and appears as an analog signal at the output.

# 1.1 Pin description

Figure 2. Pin connection

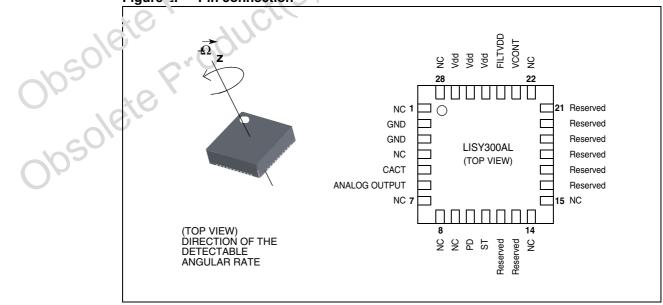


Table 2. Pin description

	Pin #	Pin Name	Function	
	1	NC	Internally not connected	
	2	GND	0V supply	
	3	GND	0V supply	
	4	NC	Internally not connected	
	5	CACT	Active filter capacitor	
	6	ANALOG OUTPUT	Rate signal output voltage	
	7-9	NC	Internally not connected	
	10	PD	Power-down (logic 0: normal mode; logic 1: power-down n'odo)	
	11	ST	Self-test (logic 0: normal mode; logic 1: self-test)	
	12-13	Reserved	Leave unconnected	
	14-15	NC	Internally not connected	
	16-21	Reserved	Leave unconnected	
	22	NC	Internally not connected	
	23	VCONT	PLL filter connection nac #1	
	24	FILTVDD	PLL filter connection pad #2	
	25	Vdd	Power supply	
	26	Vdd	Pover supply	
	27	Vdd	Fower supply	
	28	NC:	Internally not connected	
Obsolete Product(s)				

### Mechanical and electrical specifications 2

#### 2.1 **Mechanical characteristics**

Mechanical characteristics @ Vdd = 3.3 V, T = 25 °C unless otherwise noted(1) Table 3.

Symbol	Parameter	Test condition	Min.	Typ. <sup>(2)</sup>	Max.	Unit
FS	Measurement range			±300		°/s
So	Sensitivity			3.3		mV/ °/s
SoDr	Sensitivity change vs. temperature	From -40 °C to +85 °C		4		%
Voff	Zero-rate level <sup>(3)</sup>			1.65	\	57
OffDr	Zero-rate level change vs. temperature	From -40 °C to +85 °C		5	111C()	°/s
NL	Non linearity <sup>(4)</sup>	Best fit straight line		±0.8	10.	% FS
BW	-3dB bandwidth(3)(5)	C <sub>ACT</sub> = 10 nF		88)	.10	Hz
Rn	Rate noise density			0.1	111C/1	°/s / √Hz
Vt	Self-test output voltage change <sup>(6)</sup>		colle	+300	00.0	mV
Sup	Start-up time	Settling to ±5 °/s	2	300		ms
Fres	Sensing element resonant frequency		16,	4.5		kHz
Тор	Operating temperature range	ci(S)	<b>G-40</b>		+85	°C
Wh	Product weight		7	160		mg

<sup>1.</sup> The product is factory calibrate 3 at 3.3 V. The operational power supply range is specified in *Table 4*.

<sup>2.</sup> Typical specifications are not guaranteed

<sup>3.</sup> The product is capable of sensing angular rates extending from DC to the selected bandwidth

<sup>4.</sup> Guaranteed by design

<sup>5.</sup> User se'estable by external capacitor CACT

on output vo 6. "Sen'test output voltage change" is defined as  $Vout_{(Vst = logic 1)}$  -  $Vout_{(Vst = logic 0)}$ 

#### 2.2 **Electrical characteristics**

Table 4. Electrical characteristics @ Vdd =3.3 V, T=25 °C unless otherwise noted(1)

	Parameter	Test condition	Min.	Typ. <sup>(2)</sup>	Max.	Uı
Vdd	Supply voltage		2.7	3.3	3.6	,
ldd	Supply current	PD pin connected to GND		4.8		n
IddPdn	Supply current in power-down mode	PD pin connected to Vdd		1		μ
Vst	Self-test input	Logic 0 level	0		0.2*Vdd	,
V51	Sen-test input	Logic 1 level	0.8*Vdd		Vdd	
VPD	Power-down input	Logic 0 level	0		0.2*Vdd	
VPD	Fower-down input	Logic 1 level	0.8*Vdd		VdC	P
C <sub>ACT</sub>	Active low-pass filter capacitor		10	20	Mo	r
ovs	Output voltage swing <sup>(3)</sup>	lout = ±100μA	0.4	010	V <sub>dd</sub> -0.4	
C <sub>LOAD</sub>	Capacitive load drive <sup>(3)</sup>		0.4		10	r
Тор	Operating temperature range		-40	6	+85	C
	to ANALOG OUTPUT pin #6	16) 000	olege			

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### **Absolute maximum ratings** 2.3

Stresses above those listed as "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 5. **Absolute maximum ratings** 

Symbol	Ratings	Maximum value	Unit
Vdd	Supply voltage	-0.3 to 6	V
Vin	Input voltage on any control pin (PD, ST)	-0.3 to Vdd +0.3	V
۸	Acceleration (not powered)	3000 g for 0.5 ms	
A <sub>UNP</sub>	Acceleration (not powered)	10000 g for 0.1 ms	
T <sub>STG</sub>	Storage temperature range	-40 to +125	°C
ESD	Electrostatic discharge protection	2 (H5M)	kV



μορετ having can ca This is a mechanical shock sensitive device, improper handling can cause permanent



This is an ESD sensitive device, improper handling can cause permanent damage to

## 2.4 Terminology

## 2.4.1 Sensitivity

A yaw rate gyroscope is a Z-axis rate device that produces a positive-going output voltage for counterclockwise rotation around the axis normal to the package top. Sensitivity describes the gain of the sensor and can be determined by applying a defined angular velocity to it. This value changes very little over temperature and also very little over time.

## 2.4.2 Zero-rate level

Zero-rate level describes the actual output signal if there is no angular rate present. For a 3.3 V powered sensor the absolute zero-rate output is ideally 1.65 V. Zero-rate level of precise MEMS sensors is, to some extent, a result of stress to the sensor and therefore zero-rate level can slightly change after mounting the sensor onto a printed circuit board or after exposing it to extensive mechanical stress. This value changes very little over temperature and also very little over time.

### 2.4.3 Self-test

Self-test allows to test the mechanical and electric part of the sensor, allowing the seismic mass to be moved by means of an electrostatic test-force. The Self-test function is off when the ST pin is connected to GND. When the ST pin is tied to Vdd, an actuation force is applied to the sensor, emulating a definite Cericus force. In this case the sensor output will exhibit a voltage change in its DC level which is also depending on the supply voltage. When ST is active, the device output level is given by the algebraic sum of the signals produced by the velocity acting on the sensor and by the electrostatic test-force. If the output signals change within the amplitude specified in *Table 3*, then the mechanical element is working properly and the parameters of the interface chip are within the defined specification.

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LISY300AL Application hints

# 3 Application hints

C2 450nF GND **GND VDD** 9.5kOhm 100 nF R1 C1 ] 1  $\bigcirc$ Optional Low-pass filter LISY30CAL ¬ C<sub>ACT</sub> (top view) Vout<sub>YAW</sub> | 16 0.4nF Digital signals

Figure 3. LISY300AL electrical connections and external components values

Power supply d'ecoupling capacitors (100 nF ceramic or polyester + 10 µF Aluminum) should pe placed as near as possible to the device (common design practice).

The LIS /300AL allows to band limit the output rate response through the use of two first-cross on-chip filters: a switched capacitor low-pass filter, with 400Hz -3dB bandwidth, in combination with an active low-pass filter. The active filter -3 dB nominal frequency ( $f_{tA}$ ) is set through an internal resistor  $R_{ACT}$  and the external capacitor  $C_{ACT}$  (added between **CACT** pin #5 and **ANALOG OUTPUT** pin #6), by the formula:

$$f_{tA} = \frac{1}{2\pi \cdot R_{ACT} \cdot C_{ACT}}$$

The value of the internal resistor  $R_{ACT}$  is 180 k $\Omega$ , while the external capacitor  $C_{ACT}$  is used to select the signal bandwidth. The sensed frequency range spans from DC up to the selected bandwidth.

In order to further reduce high-frequency noise, the LISY300AL supports an additional optional low-pass filter on **ANALOG OUTPUT** pin #6 (*Figure 3*). The cutoff frequency (f<sub>tP</sub>) is given by the formula:

$$f_{tP} = \frac{1}{2\pi \cdot R_{OPT} \cdot C_{OPT}}$$

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**Application hints** LISY300AL

> The LISY300AL IC includes a PLL (phase locked loop) circuit to synchronize driving and sensing interfaces. Capacitors and resistors must be added at the FILTVDD and VCONT pads (as shown in Figure 3) to implement a second-order low-pass filter. Table 6 summarizes the PLL low-pass filter components' values.

Table 6. PLL low-pass filter components' values

Component	Value
C1	450 nF ± 10%
C2	9 nF ± 10%
R1	9.5 kΩ± 10%

#### 3.1 Soldering information

Jec J-S75-V Dec J-The LGA package is compliant with the ECOPACK®, RoHS and "Green' standard. It is qualified for soldering heat resistance according to JEDEC J-STD-320C.

Land pattern and soldering recommendations are available at www.st.com/mems

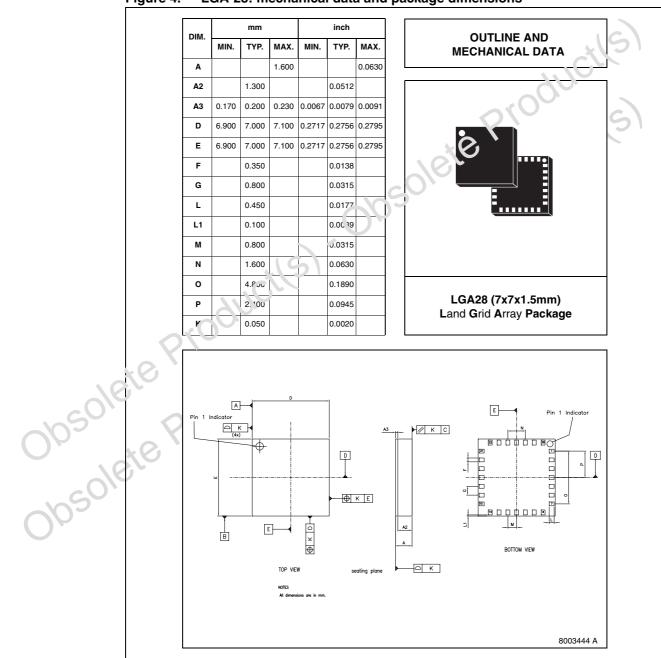
LISY300AL Package information

# 4 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK® is an ST trademark.

ECOPACK® specifications are available at: www.st.com.

Figure 4. LGA-28: mechanical data and package dimensions



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Revision history LISY300AL

# 5 Revision history

Table 7. Document revision history

Date	Revision	Changes
29-May-08	1	Initial release

Obsolete Product(s) Obsolete Product(s)
Obsolete Product(s)
Obsolete Product(s)

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